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SF31 - SF39

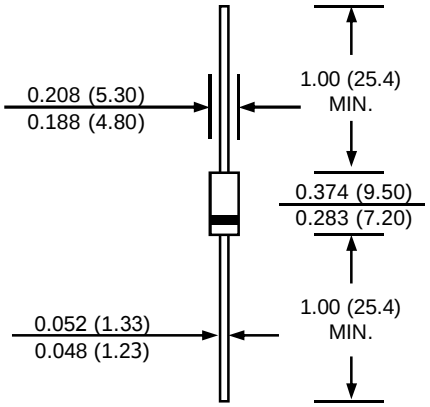
SUPER FAST RECTIFIER DIODES

PRV : 50 - 1000 Volts
Io : 3.0 Amperes

FEATURES :
* High current capability
* High surge current capability
* High reliability
* Low reverse current
* Low forward voltage drop
* Super fast recovery time
* Pb / RoHS Free

MECHANICAL DATA :
* Case : DO-201AD Molded plastic
* Epoxy : UL94V-O rate flame retardant
* Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
* Polarity : Color band denotes cathode end
* Mounting position : Any
* Weight : 1.16 grams

DO - 201AD



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

RATING	SYMBOL	SF31	SF32	SF33	SF34	SF35	SF36	SF37	SF38	SF39	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	$I_{F(AV)}$	3.0									A
Maximum Peak Forward Surge Current, 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	65									A
Maximum Peak Forward Voltage at I_F = 3.0 A.	V_F	0.95				1.7			4.0		V
Maximum DC Reverse Current Tj = 25 °C	I_R	10									µA
at Rated DC Blocking Voltage Tj = 100 °C	$I_{R(H)}$	500									µA
Maximum Reverse Recovery Time (Note 1)	Trr	35									ns
Typical Junction Capacitance (Note 2)	C_J	50									pf
Junction Temperature Range	T_J	- 65 to + 150									°C
Storage Temperature Range	T_{STG}	- 65 to + 150									°C

Notes :

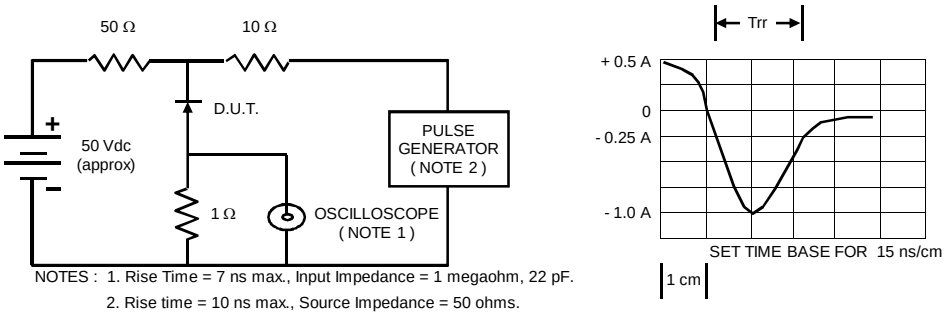
(1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}

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RATING AND CHARACTERISTIC CURVES (SF31 - SF39)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
2. Rise time = 10 ns max., Source Impedance = 50 ohms.
3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

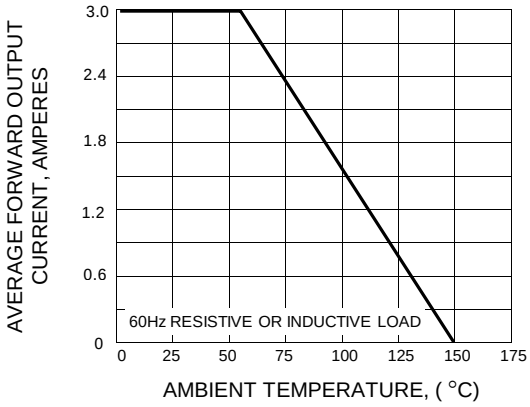


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

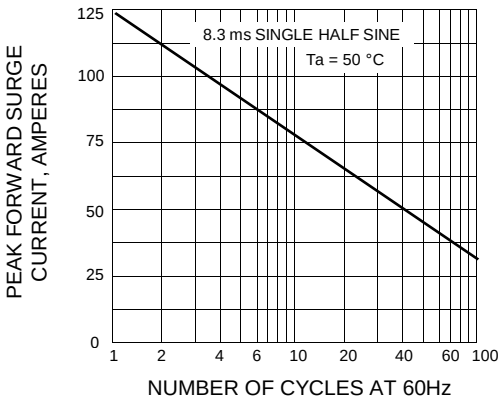


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

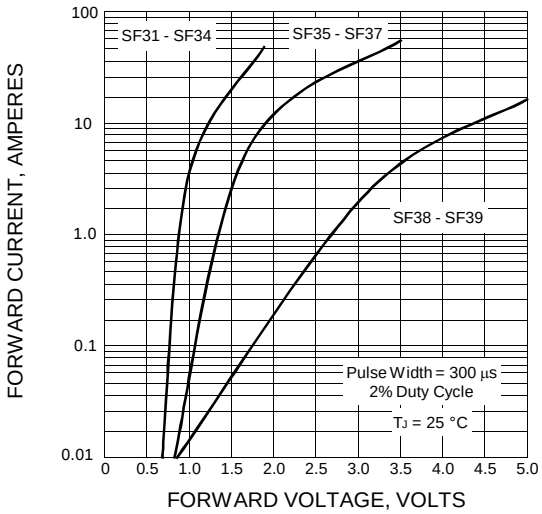
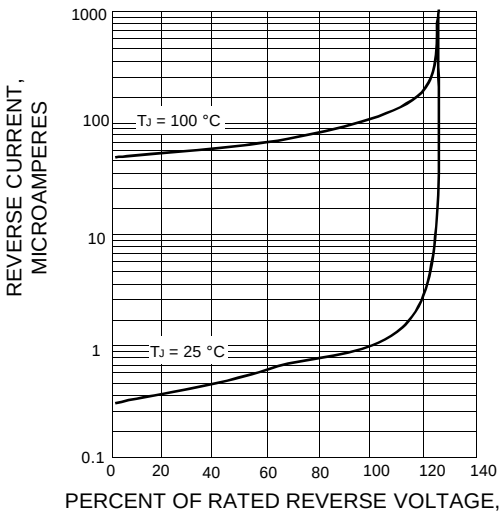


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



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